

FEATURES

120 mA current sink
 Available in 3 × 3 array WLCSP package
 2-wire (I²C-compatible) 1.8 V serial interface
 10-bit resolution
 Integrated current sense resistor
 2.7 V to 5.5 V power supply
 Guaranteed monotonic over all codes
 Power-down to 0.5 μA typical
 Internal reference
 Ultralow noise preamplifier
 Power-down function
 Power-on reset

CONSUMER APPLICATIONS

Lens autofocus
 Image stabilization
 Optical zoom
 Shutters
 Iris/exposure
 Neutral density (ND) filters
 Lens covers
 Camera phones
 Digital still cameras
 Camera modules
 Digital video cameras/camcorders
 Camera-enabled devices
 Security cameras
 Web/PC cameras

INDUSTRIAL APPLICATIONS

Heater controls
 Fan controls
 Cooler (Peltier) controls
 Solenoid controls
 Valve controls
 Linear actuator controls
 Light controls
 Current loop controls

GENERAL DESCRIPTION

The AD5821 is a single 10-bit digital-to-analog converter with 120 mA output current sink capability. It features an internal reference and operates from a single 2.7 V to 5.5 V supply. The DAC is controlled via a 2-wire (I²C-compatible) serial interface that operates at clock rates up to 400 kHz.

The AD5821 incorporates a power-on reset circuit that ensures that the DAC output powers up to 0 V and remains there until a valid write takes place. It has a power-down feature that reduces the current consumption of the device to 1 μA maximum.

The AD5821 is designed for autofocus, image stabilization, and optical zoom applications in camera phones, digital still cameras, and camcorders.

The AD5821 also has many industrial applications, such as controlling temperature, light, and movement, over the range of -40°C to +85°C without derating.

The I²C address for the AD5821 is 0x18.

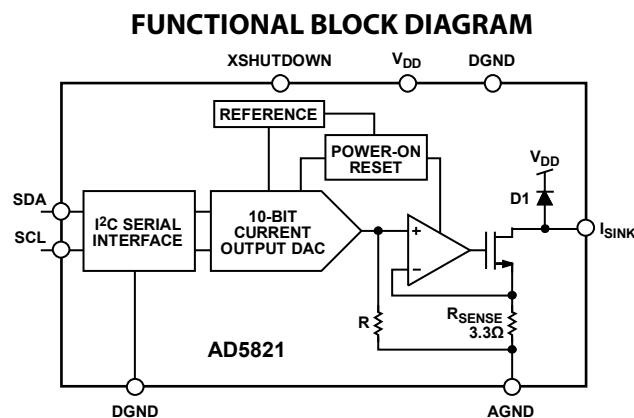


Figure 1.

Rev. 0

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A.
 Tel: 781.329.4700 www.analog.com
 Fax: 781.461.3113 ©2007 Analog Devices, Inc. All rights reserved.

TABLE OF CONTENTS

Features	1	Typical Performance Characteristics	7
Consumer Applications	1	Terminology	10
Industrial Applications	1	Theory of Operation	11
General Description	1	Serial Interface	11
Functional Block Diagram	1	I ² C Bus Operation	11
Revision History	2	Data Format	11
Specifications.....	3	Power Supply Bypassing and Grounding.....	12
AC Specifications.....	4	Applications Information	14
Timing Specifications	4	Outline Dimensions	15
Absolute Maximum Ratings.....	5	Ordering Guide	15
Pin Configuration and Function Descriptions.....	6		

REVISION HISTORY

1/07—Revision 0: Initial Version

SPECIFICATIONS

$V_{DD} = 2.7\text{ V to }5.5\text{ V}$, $AGND = DGND = 0\text{ V}$, load resistance $R_L = 25\ \Omega$ connected to V_{DD} ; all specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Table 1.

Parameter	B Version ¹			Unit	Test Conditions/Comments
	Min	Typ	Max		
DC PERFORMANCE					
Resolution		10		Bits	$V_{DD} = 3.6\text{ V to }4.5\text{ V}$; device operates over $2.7\text{ V to }5.5\text{ V}$ with reduced performance 117 $\mu\text{A/LSB}$ Guaranteed monotonic over all codes All 0s loaded to DAC @ 25°C
Relative Accuracy ²		± 1.5	± 4	LSB	
Differential Nonlinearity ^{2, 3}			± 1	LSB	
Zero-Code Error ^{2, 4}	0	1	5	mA	
Offset Error @ Code 16 ²		0.5		mA	
Gain Error ²			± 0.6	% of FSR	
Offset Error Drift ^{4, 5}		10		$\mu\text{A}/^\circ\text{C}$	
Gain Error Drift ^{2, 5}		± 0.2	± 0.5	LSB/ $^\circ\text{C}$	
OUTPUT CHARACTERISTICS					
Minimum Sink Current ⁴		3		mA	XSHUTDOWN = 0 Output voltage range over which maximum 120 mA sink current is available Output voltage range over which 90 mA sink current is available To 10% of FS, coming out of power-down mode; $V_{DD} = 5\text{ V}$
Maximum Sink Current		120		mA	
Output Current During XSHUTDOWN		80		nA	
Output Compliance ⁵	0.6		V_{DD}	V	
Output Compliance ⁵	0.48		V_{DD}	V	
Power-Up Time		20		μs	
LOGIC INPUTS (XSHUTDOWN)⁵					
Input Current			± 1	μA	$V_{DD} = 2.7\text{ V to }5.5\text{ V}$ $V_{DD} = 2.7\text{ V to }5.5\text{ V}$
Input Low Voltage, V_{INL}			0.54	V	
Input High Voltage, V_{INH}	1.3			V	
Pin Capacitance		3		pF	
LOGIC INPUTS (SCL, SDA)⁵					
Input Low Voltage, V_{INL}	-0.3		+0.54	V	$V_{DD} = 2.7\text{ V to }3.6\text{ V}$
Input High Voltage, V_{INH}	1.26		$V_{DD} + 0.3$	V	$V_{DD} = 2.7\text{ V to }3.6\text{ V}$
Input Low Voltage, V_{INL}	-0.3		+0.54	V	$V_{DD} = 3.6\text{ V to }5.5\text{ V}$
Input High Voltage, V_{INH}	1.4		$V_{DD} + 0.3$	V	$V_{DD} = 3.6\text{ V to }5.5\text{ V}$
Input Leakage Current, I_{IN}			± 1	μA	$V_{IN} = 0\text{ V to }V_{DD}$
Input Hysteresis, V_{HYST}	$0.05 V_{DD}$			V	
Digital Input Capacitance, C_{IN}		6		pF	
Glitch Rejection ⁶			50	ns	Pulse width of spike suppressed
POWER REQUIREMENTS					
V_{DD}	2.7		5.5	V	I_{DD} specification is valid for all DAC codes $V_{INH} = 1.8\text{ V}$, $V_{INL} = \text{GND}$, $V_{DD} = 3.6\text{ V}$ $V_{INH} = 1.8\text{ V}$, $V_{INL} = \text{GND}$
I_{DD} (Normal Mode)		2.5	4	mA	
$V_{DD} = 2.7\text{ V to }3.6\text{ V}$				mA	
I_{DD} (Power-Down Mode) ⁷		0.5		μA	

¹ Temperature range is as follows: B Version = $-30^\circ\text{C to }+85^\circ\text{C}$.

² See the Terminology section.

³ Linearity is tested using a reduced code range: Code 32 to Code 1023.

⁴ To achieve near zero output current, use the power-down feature.

⁵ Guaranteed by design and characterization; not production tested. XSHUTDOWN is active low. SDA and SCL pull-up resistors are tied to 1.8 V.

⁶ Input filtering on both the SCL and the SDA inputs suppresses noise spikes that are less than 50 ns.

⁷ XSHUTDOWN is active low.

AD5821

AC SPECIFICATIONS

$V_{DD} = 2.7\text{ V}$ to 5.5 V , $AGND = DGND = 0\text{ V}$, load resistance $R_L = 25\ \Omega$ connected to V_{DD} , unless otherwise noted.

Table 2.

Parameter	B Version ^{1, 2}			Unit	Test Conditions/Comments
	Min	Typ	Max		
Output Current Settling Time		250		μs	$V_{DD} = 3.6\text{ V}$, $R_L = 25\ \Omega$, $L_L = 680\ \mu\text{H}$, 1/4 scale to 3/4 scale change (0x100 to 0x300)
Slew Rate		0.3		$\text{mA}/\mu\text{s}$	
Major Code Change Glitch Impulse		0.15		$\text{nA}\cdot\text{s}$	1 LSB change around major carry
Digital Feedthrough ³		0.06		$\text{nA}\cdot\text{s}$	

¹ Temperature range is as follows: B Version = -40°C to $+85^\circ\text{C}$.

² Guaranteed by design and characterization; not production tested.

³ See the Terminology section.

TIMING SPECIFICATIONS

$V_{DD} = 2.7\text{ V}$ to 3.6 V . All specifications T_{MIN} to T_{MAX} , unless otherwise noted.

Table 3.

Parameter ¹	B Version Limit at T_{MIN} , T_{MAX}	Unit	Description
f_{SCL}	400	kHz max	SCL clock frequency
t_1	2.5	$\mu\text{s min}$	SCL cycle time
t_2	0.6	$\mu\text{s min}$	t_{HIGH} , SCL high time
t_3	1.3	$\mu\text{s min}$	t_{LOW} , SCL low time
t_4	0.6	$\mu\text{s min}$	$t_{HD, STA}$, start/repeated start condition hold time
t_5	100	ns min	$t_{SU, DAT}$, data setup time
t_6^2	0.9	$\mu\text{s max}$	$t_{HD, DAT}$, data hold time
	0	$\mu\text{s min}$	
t_7	0.6	$\mu\text{s min}$	$t_{SU, STA}$, setup time for repeated start
t_8	0.6	$\mu\text{s min}$	$t_{SU, STO}$, stop condition setup time
t_9	1.3	$\mu\text{s min}$	t_{BUF} , bus free time between a stop condition and a start condition
t_{10}	300	ns max	t_R , rise time of both SCL and SDA when receiving
	0	ns min	May be CMOS driven
t_{11}	250	ns max	t_F , fall time of SDA when receiving
	300	ns max	t_F , fall time of both SCL and SDA when transmitting
C_B	$20 + 0.1 C_B^3$	ns min	
	400	pF max	Capacitive load for each bus line

¹ Guaranteed by design and characterization; not production tested.

² A master device must provide a hold time of at least 300 ns for the SDA signal (referred to the $V_{INH, MIN}$ of the SCL signal) to bridge the undefined region of the SCL falling edge.

³ C_B is the total capacitance of one bus line in pF. t_R and t_F are measured between $0.3 V_{DD}$ and $0.7 V_{DD}$.

Timing Diagram

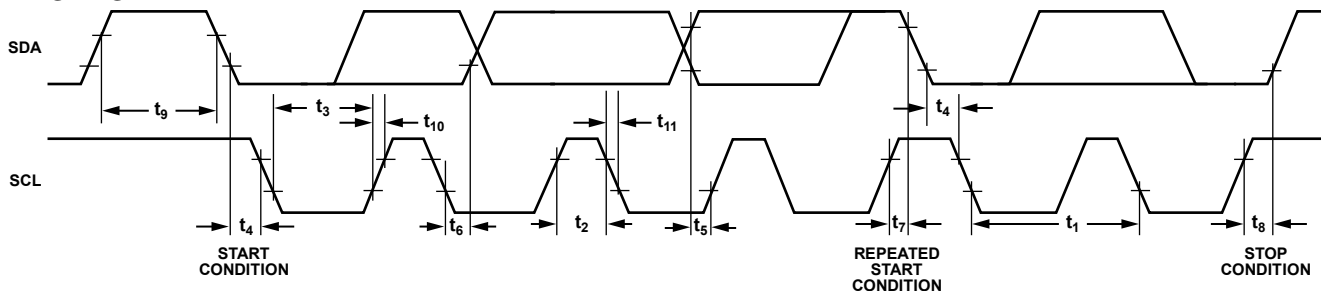


Figure 2. 2-Wire Serial Interface Timing Diagram

05950-002

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 4.

Parameter	Rating
V_{DD} to AGND	-0.3 V to +5.5 V
V_{DD} to DGND	-0.3 V to $V_{DD} + 0.3$ V
AGND to DGND	-0.3 V to +0.3 V
SCL, SDA to DGND	-0.3 V to $V_{DD} + 0.3$ V
XSHUTDOWN to DGND	-0.3 V to $V_{DD} + 0.3$ V
I_{SINK} to AGND	-0.3 V to $V_{DD} + 0.3$ V
Operating Temperature Range Industrial (B Version)	-30°C to $+85^\circ\text{C}$
Storage Temperature Range	-65°C to $+150^\circ\text{C}$
Junction Temperature ($T_{J\text{ MAX}}$)	150°C
WLFCS Power Dissipation	$(T_{J\text{ MAX}} - T_A)/\theta_{JA}$
θ_{JA} Thermal Impedance ¹ Mounted on 4-Layer Board	95°C/W
Lead Temperature, Soldering Maximum Peak Reflow Temperature ²	$260^\circ\text{C} (\pm 5^\circ\text{C})$

¹ To achieve the optimum θ_{JA} , it is recommended that the AD5821 be soldered on a 4-layer board.

² As per JEDEC J-STD-020C.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

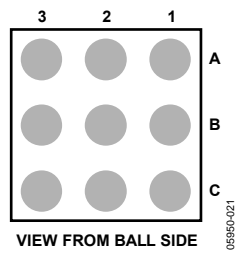


Figure 3. 9-Ball WLCSP Pin Configuration

Table 5. 9-Ball WLCSP Pin Function Description

Ball Number	Mnemonic	Description
A1	I _{SINK}	Output Current Sink.
A2	NC	No Connection.
A3	XSHUTDOWN	Power-Down. Asynchronous power-down signal, active low.
B1	AGND	Analog Ground Pin.
B2	DGND	Digital Ground Pin.
B3	SDA	I ² C Interface Signal.
C1	DGND	Digital Ground Pin.
C2	V _{DD}	Digital Supply Voltage.
C3	SCL	I ² C Interface Signal.

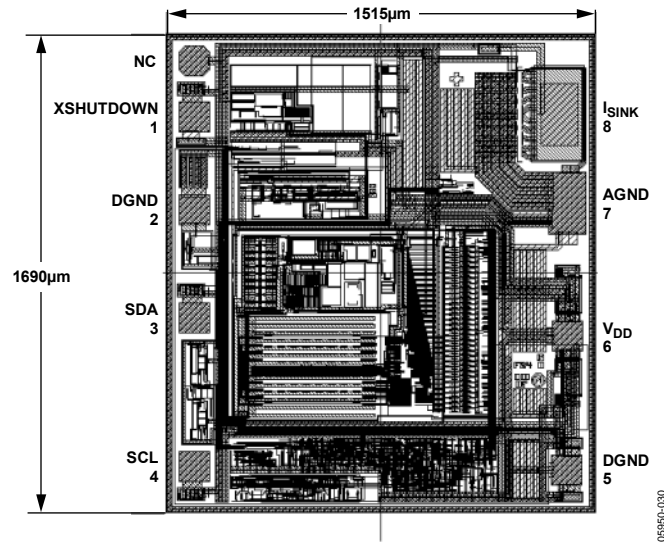


Figure 4. Metallization Photo
Dimensions shown in microns (μm)

TYPICAL PERFORMANCE CHARACTERISTICS

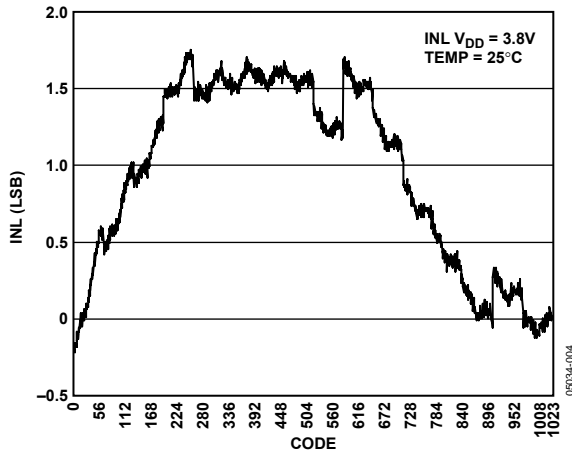


Figure 5. Typical INL vs. Code Plot

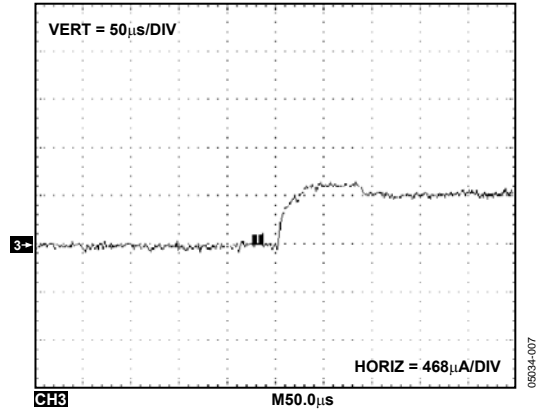


Figure 8. Settling Time for a 4-LSB Step ($V_{DD} = 3.6\text{ V}$)

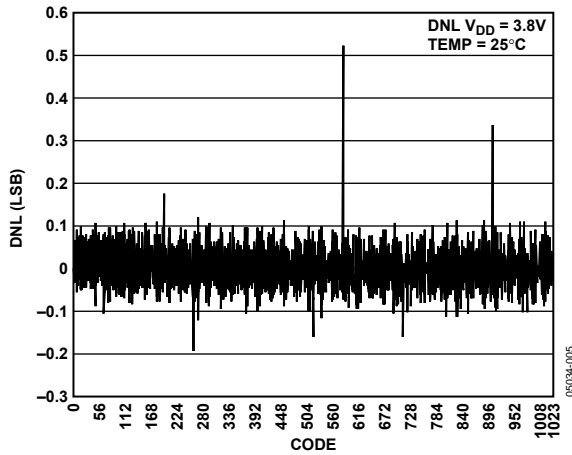


Figure 6. Typical DNL vs. Code Plot

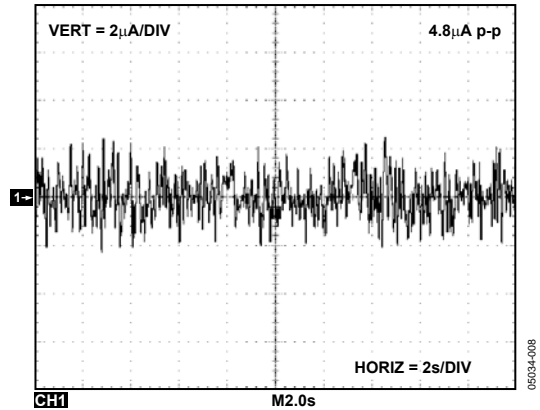


Figure 9. 0.1 Hz to 10 Hz Noise Plot ($V_{DD} = 3.6\text{ V}$)

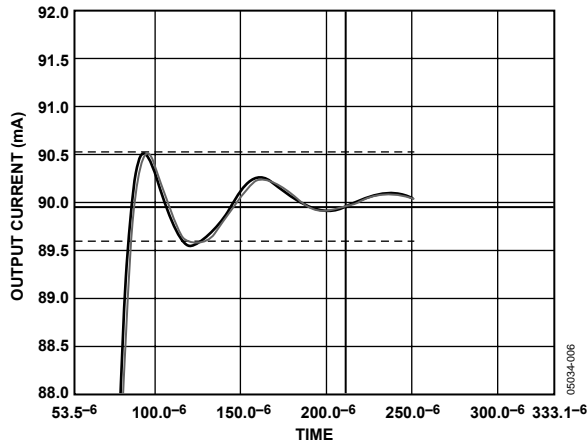


Figure 7. $\frac{1}{4}$ to $\frac{3}{4}$ Scale Settling Time ($V_{DD} = 3.6\text{ V}$)

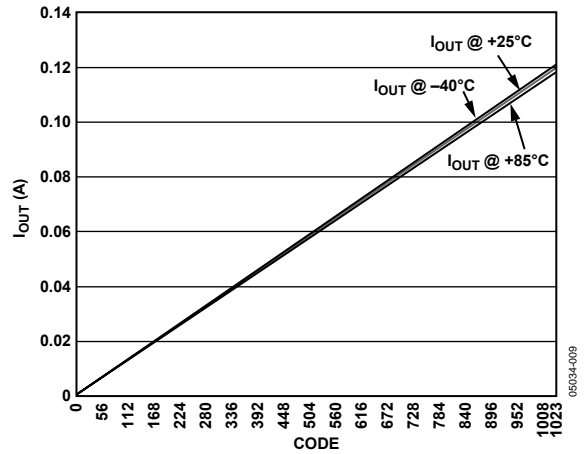


Figure 10. Sink Current vs. Code vs. Temperature ($V_{DD} = 3.6\text{ V}$)

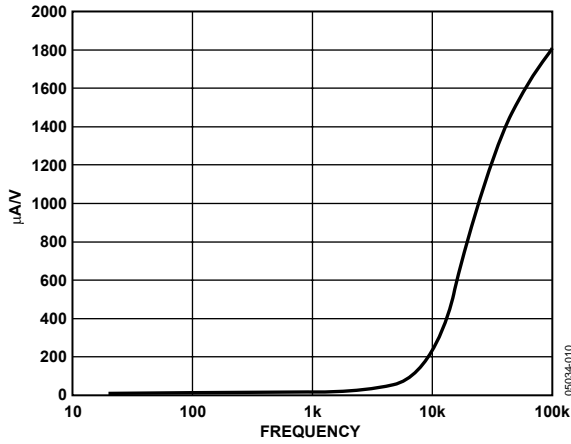


Figure 11. AC Power Supply Rejection ($V_{DD} = 3.6\text{ V}$)

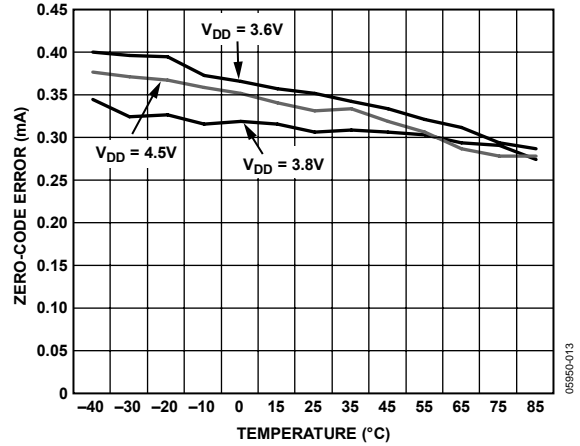


Figure 14. Zero-Code Error vs. Supply Voltage vs. Temperature

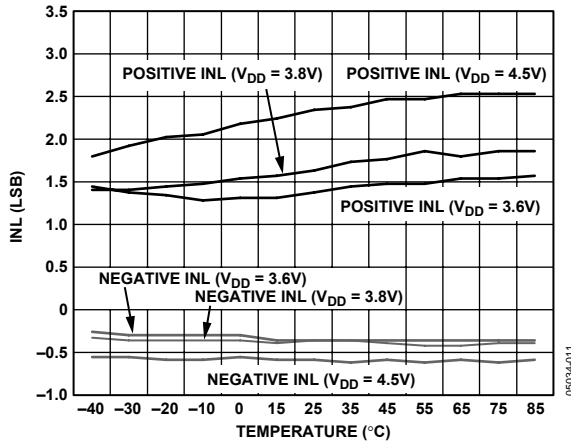


Figure 12. INL vs. Temperature vs. Supply Voltage

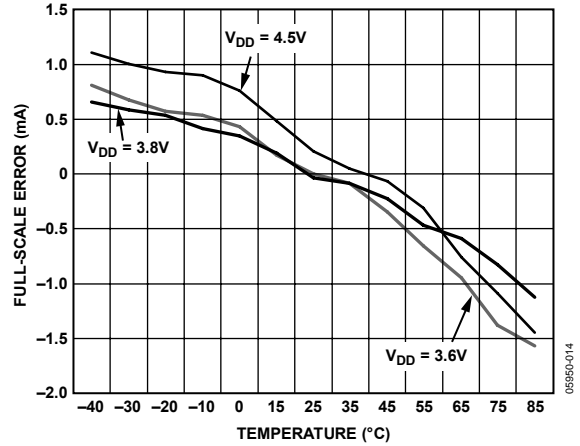


Figure 15. Full-Scale Error vs. Temperature vs. Supply Voltage

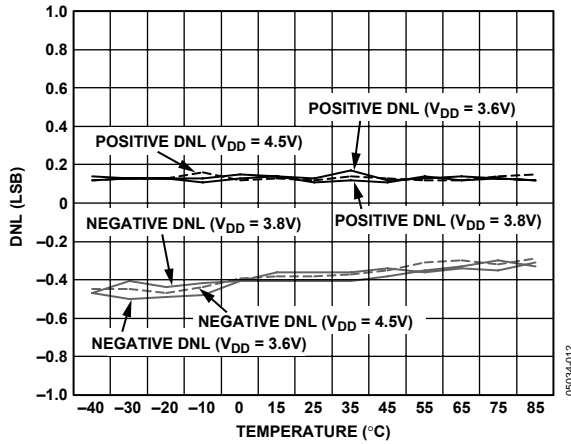


Figure 13. DNL vs. Temperature vs. Supply Voltage

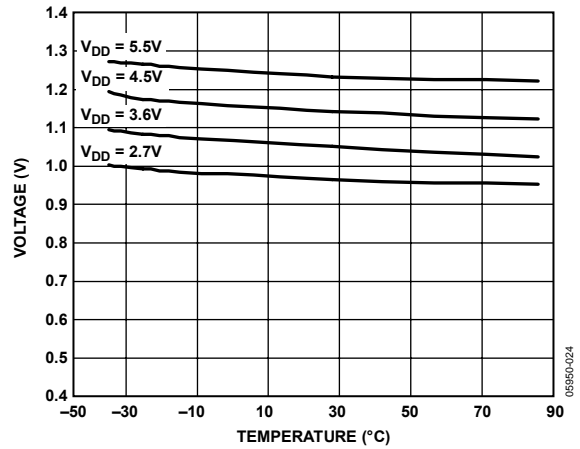


Figure 16. SCL and SDA Logic High Level (V_{INH}) vs. Supply Voltage and Temperature

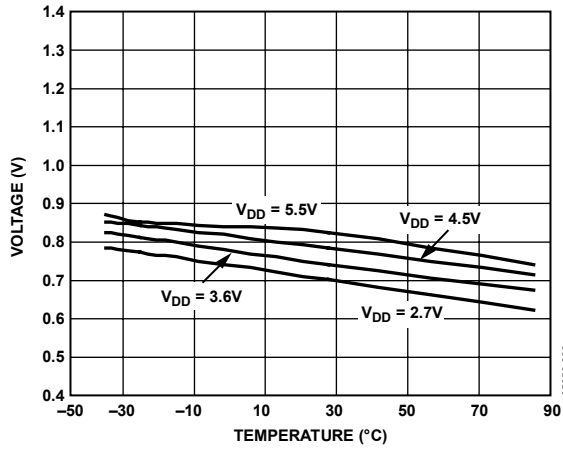


Figure 17. SCL and SDA Logic Low Level (V_{INL}) vs. Supply Voltage and Temperature

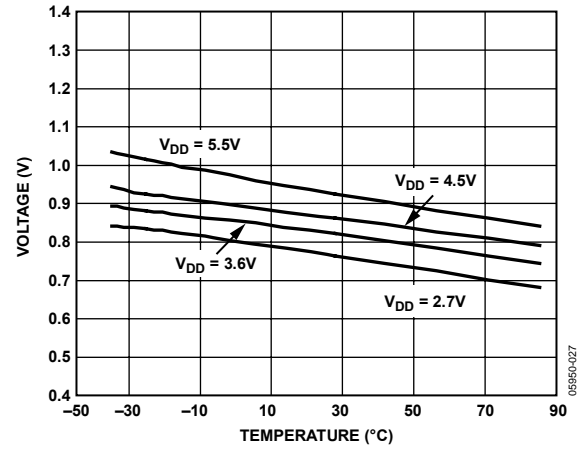


Figure 19. DNL vs. XSHUTDOWN Logic Low Level (V_{INL}) vs. Supply Voltage and Temperature

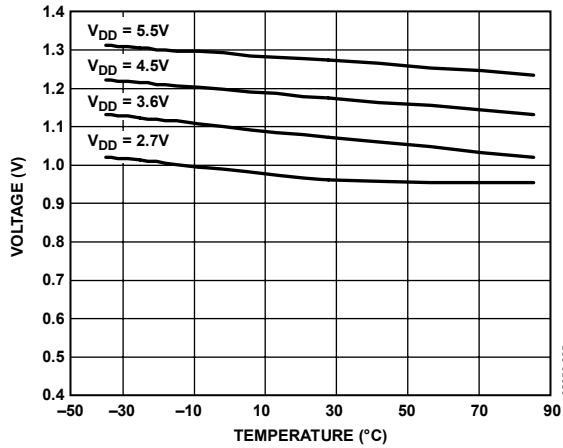


Figure 18. XSHUTDOWN Logic High Level (V_{INH}) vs. Supply Voltage and Temperature

TERMINOLOGY

Relative Accuracy

For the DAC, relative accuracy or integral nonlinearity is a measurement of the maximum deviation, in LSB, from a straight line passing through the endpoints of the DAC transfer function. A typical INL vs. code plot is shown in Figure 5.

Differential Nonlinearity (DNL)

Differential nonlinearity is the difference between the measured change and the ideal 1 LSB change between any two adjacent codes. A specified differential nonlinearity of ± 1 LSB maximum ensures monotonicity. This DAC is guaranteed monotonic by design. A typical DNL vs. code plot is shown in Figure 6.

Zero-Code Error

Zero-code error is a measurement of the output error when zero code (0x0000) is loaded to the DAC register. Ideally, the output is 0 mA. The zero-code error is always positive in the AD5821 because the output of the DAC cannot go below 0 mA. This is due to a combination of the offset errors in the DAC and output amplifier. Zero-code error is expressed in milliamperes (mA).

Gain Error

Gain error is a measurement of the span error of the DAC. It is the deviation in slope of the DAC transfer characteristic from the ideal, expressed as a percent of the full-scale range.

Gain Error Drift

Gain error drift is a measurement of the change in gain error with changes in temperature. It is expressed in LSB/ $^{\circ}$ C.

Digital-to-Analog Glitch Impulse

This is the impulse injected into the analog output when the input code in the DAC register changes state. It is normally specified as the area of the glitch in nanoamperes per second (nA-s) and is measured when the digital input code is changed by 1 LSB at the major carry transition.

Digital Feedthrough

Digital feedthrough is a measurement of the impulse injected into the analog output of the DAC from the digital inputs of the DAC, but it is measured when the DAC output is not updated. It is specified in nanoamperes per second (nA-s) and measured with a full-scale code change on the data bus, that is, from all 0s to all 1s and vice versa.

Offset Error

Offset error is a measurement of the difference between I_{SINK} (actual) and I_{OUT} (ideal) in the linear region of the transfer function, expressed in milliamperes (mA). Offset error is measured on the AD5821 with Code 16 loaded into the DAC register.

Offset Error Drift

Offset error drift is a measurement of the change in offset error with a change in temperature. It is expressed in microvolts per degree Celsius ($\mu\text{V}/^{\circ}\text{C}$).

THEORY OF OPERATION

The AD5821 is a fully integrated, 10-bit digital-to-analog converter (DAC) with 120 mA output current sink capability. It is intended for driving voice coil actuators in applications such as lens autofocus, image stabilization, and optical zoom. The circuit diagram is shown in Figure 20. A 10-bit current output DAC coupled with Resistor R generates the voltage that drives the noninverting input of the operational amplifier. This voltage also appears across the R_{SENSE} resistor and generates the sink current required to drive the voice coil.

Resistor R and Resistor R_{SENSE} are interleaved and matched. Therefore, the temperature coefficient and any nonlinearities over temperature are matched, and the output drift over temperature is minimized. Diode D1 is an output protection diode.

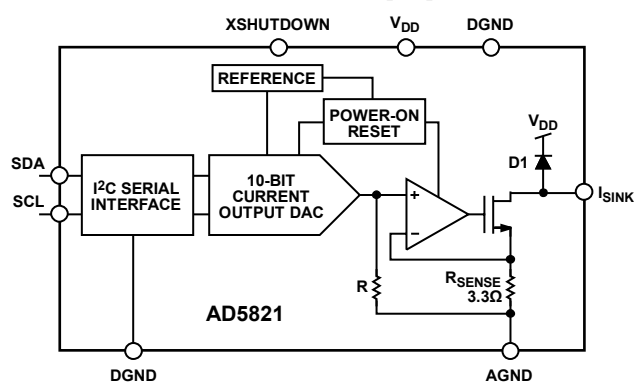


Figure 20. Block Diagram Showing Connection to Voice Coil

SERIAL INTERFACE

The AD5821 is controlled using the industry-standard I²C 2-wire serial protocol. Data can be written to or read from the DAC at data rates of up to 400 kHz. After a read operation, the contents of the input register are reset to all 0s.

I²C BUS OPERATION

An I²C bus operates with one or more master devices that generate the serial clock (SCL) and read and write data on the serial data line (SDA) to and from slave devices such as the AD5821. All devices on an I²C bus have their SDA pin connected to the SDA line and their SCL pin connected to the SCL line of the master device. I²C devices can only pull the bus lines low; pulling high is achieved by pull-up resistors, R_P . The value of R_P depends on the data rate, bus capacitance, and the maximum load current that the I²C device can sink (3 mA for a standard device).

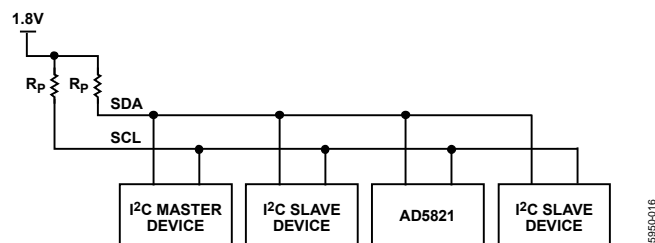


Figure 21. Typical I²C Bus

When the bus is idle, SCL and SDA are both high. The master device initiates a serial bus operation by generating a start condition, which is defined as a high-to-low transition on the SDA low while SCL is high. The slave device connected to the bus responds to the start condition and shifts in the next eight data bits under control of the serial clock. These eight data bits consist of a 7-bit address, plus a read/write (R/\overline{W}) bit that is 0 if data is to be written to a device, and 1 if data is to be read from a device. Each slave device on an I²C bus must have a unique address. The address of the AD5821 is 0001100; however, 0001101, 0001110, and 0001111 address the part because the last two bits are unused/don't cares (see Figure 22 and Figure 23). Because the address plus the R/\overline{W} bit always equals eight bits of data, the write address of the AD5821 is 00011000 (0x18) and the read address is 00011001 (0x19) (see Figure 22 and Figure 23).

At the end of the address data, after the R/\overline{W} bit, the slave device that recognizes its own address responds by generating an acknowledge (ACK) condition. This is defined as the slave device pulling SDA low while SCL is low before the ninth clock pulse and keeping it low during the ninth clock pulse. Upon receiving ACK, the master device can clock data into the AD5821 in a write operation, or it can clock it out in a read operation. Data must change either during the low period of the clock (because SDA transitions during the high period define a start condition, as described previously), or during a stop condition, as described in the Data Format section.

I²C data is divided into blocks of eight bits, and the slave generates an ACK at the end of each block. Because the AD5821 requires 10 bits of data, two data-words must be written to it when a write operation occurs, or read from it when a read operation occurs. At the end of a read or write operation, the AD5821 acknowledges the second data byte. The master generates a stop condition, defined as a low-to-high transition on SDA while SCL is high, to end the transaction.

DATA FORMAT

Data is written to the AD5821 high byte first, MSB first, and is shifted into the 16-bit input register. After all data is shifted in, data from the input register is transferred to the DAC register.

Because the DAC requires only 10 bits of data, not all bits of the input register data are used. The MSB is reserved for an active-high, software-controlled, power-down function. Bit 14 is unused; Bit 13 to Bit 4 correspond to the DAC data bits, Bit 9 to Bit 0. Bit 3 to Bit 0 are unused.

During a read operation, data is read in the same bit order.

AD5821

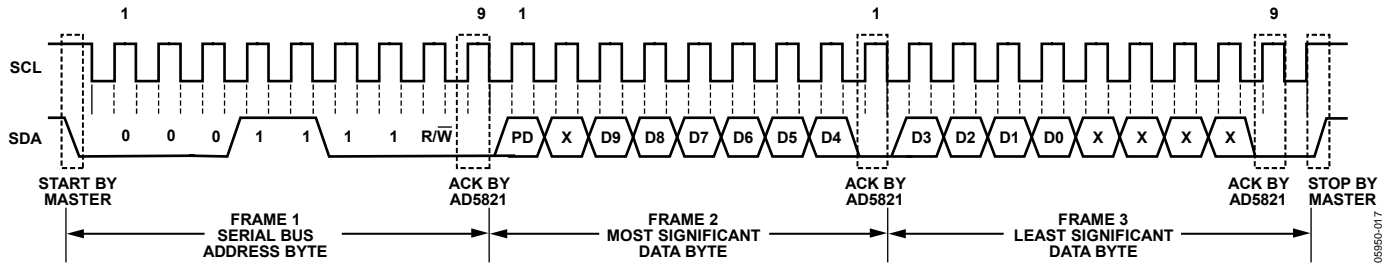


Figure 22. Write Operation

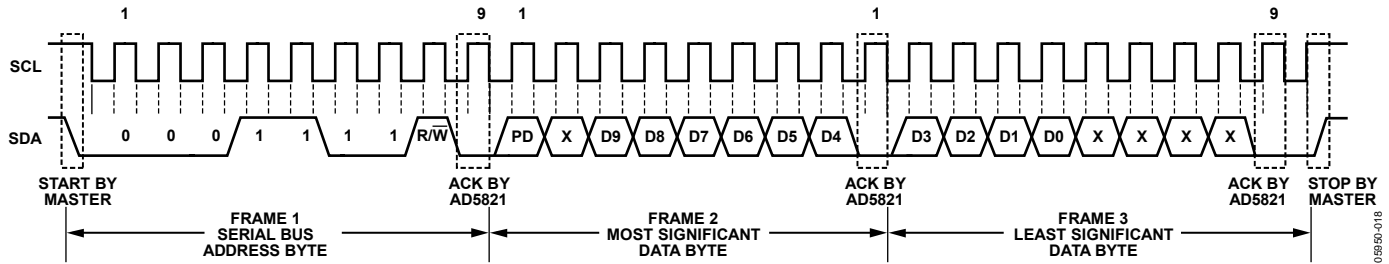


Figure 23. Read Operation

Table 6. Data Format¹

Serial Data-Words	High Byte								Low Byte							
Serial Data Bits	SD7	SD6	SD5	SD4	SD3	SD2	SD1	SD0	SD7	SD6	SD5	SD4	SD3	SD2	SD1	SD0
Input Register	R15	R14	R13	R12	R11	R10	R9	R8	R7	R6	R5	R4	R3	R2	R1	R0
Function	XSHUTDOWN	X	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	X	X	X	X

¹ XSHUTDOWN = soft power-down; X = unused/don't care; and D9 to D0 = DAC data.

POWER SUPPLY BYPASSING AND GROUNDING

When accuracy is important in an application, it is beneficial to consider power supply and ground return layout on the PCB. The PCB for the AD5821 should have separate analog and digital power supply sections. Where shared AGND and DGND is necessary, the connection of grounds should be made at only one point, as close as possible to the AD5821.

Special attention should be paid to the layout of the AGND return path and, it should be tracked between the voice coil motor and I_{SINK} to minimize any series resistance. Figure 24 shows the output current sink of the AD5821 and illustrates the importance of reducing the effective series impedance of AGND and the track resistance between the motor and I_{SINK} . The voice coil is modeled as Inductor L_C and Resistor R_C . The current through the voice coil is effectively a dc current that results in a voltage drop, V_C , when the AD5821 is sinking current. The effect of any series inductance is minimal.

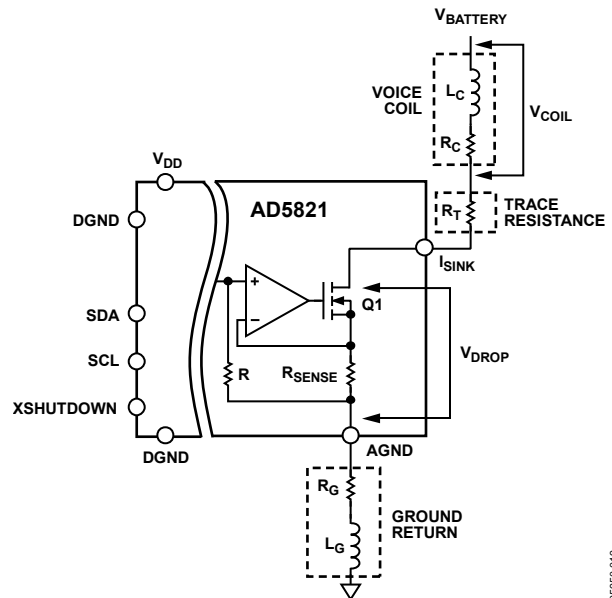


Figure 24. Effect of PCB Trace Resistance and Inductance

When sinking the maximum current of 120 mA, the maximum voltage drop allowed across R_{SENSE} is 400 mV, and the minimum drain to source voltage of Q1 is 200 mV. This means that the AD5821 output has a compliance voltage of 600 mV. If V_{DROP} falls below 600 mV, the output transistor, Q1, can no longer operate properly and I_{SINK} may not be maintained as a constant.

When sinking 90 mA, the maximum voltage drop allowed across R_{SENSE} is 300 mV, and the minimum drain to source voltage of Q1 is 180 mV. This means that the AD5821 output has a compliance voltage of 480 mV. If V_{DROP} falls below 480 mV, the output transistor, Q1, can no longer operate properly and I_{SINK} may not be maintained as a constant. As I_{SINK} decreases, the voltage required across the transistor, Q1, also decreases and, therefore, lower supplies can be used with the voice coil motor.

As the current increases to 120 mA through the voice coil, V_C increases. V_{DROP} decreases and eventually approaches the minimum specified compliance voltage of 600 mV (or 480 mV, if $I_{SINK} = 90$ mA). The ground return path is modeled by the components R_G and L_G . The track resistance between the voice coil and the AD5821 is modeled as R_T . The inductive effects of L_G influence R_{SENSE} and R_C equally, and because the current is maintained as a constant, it is not as critical as the purely resistive component of the ground return path. When the maximum sink current is flowing through the motor, the resistive elements, R_T and R_G , may have an impact on the voltage headroom of Q1 and could, in turn, limit the maximum value of R_C because of voltage compliance.

For example, if

$$V_{BATTERY} = 3.6 \text{ V}$$

$$R_G = 0.5 \ \Omega$$

$$R_T = 0.5 \ \Omega$$

$$I_{SINK} = 120 \text{ mA}$$

$$V_{DROP} = 600 \text{ mV (the compliance voltage)}$$

Then the largest value of resistance of the voice coil, R_C , is

$$R_C = \frac{V_{BAT} - [V_{DROP} + (I_{SINK} \times R_T) + (I_{SINK} \times R_G)]}{I_{SINK}} =$$

$$\frac{3.6 \text{ V} - [600 \text{ mV} + 2 \times (120 \text{ mA} \times 0.5 \ \Omega)]}{120 \text{ mA}} = 24 \ \Omega$$

Using another example, if

$$V_{BATTERY} = 3.6 \text{ V}$$

$$R_G = 0.5 \ \Omega$$

$$R_T = 0.5 \ \Omega$$

$$I_{SINK} = 90 \text{ mA}$$

$$V_{DROP} = 480 \text{ mV (the compliance voltage specification at 90 mA)}$$

Then the largest value of resistance of the voice coil, R_C , is

$$R_C = \frac{V_{BAT} - [V_{DROP} + (I_{SINK} \times R_T) + (I_{SINK} \times R_G)]}{I_{SINK}} =$$

$$\frac{3.6 \text{ V} - [480 \text{ mV} + 2 \times (90 \text{ mA} \times 0.5 \ \Omega)]}{90 \text{ mA}} = 33.66 \ \Omega$$

For this reason, it is important to minimize any series impedance on both the ground return path and interconnect between the AD5821 and the motor. It is also important to note that for lower values of I_{SINK} , the compliance voltage of the output stage also decreases. This decrease allows the user to either use voice coil motors with high resistance values or decrease the power supply voltage on the voice coil motor. The compliance voltage decreases as the I_{SINK} current decreases.

The power supply of the AD5821, or the regulator used to supply the AD5821, should be decoupled. Best practice power supply decoupling recommends that the power supply be decoupled with a 10 μF capacitor. Ideally, this 10 μF capacitor should be of a tantalum bead type. However, if the power supply or regulator supply is well regulated and clean, such decoupling may not be required. The AD5821 should be decoupled locally with a 0.1 μF ceramic capacitor, and this 0.1 μF capacitor should be located as close as possible to the V_{DD} pin. The 0.1 μF capacitor should be ceramic with a low effective series resistance and effective series inductance. The 0.1 μF capacitor provides a low impedance path to ground for high transient currents.

The power supply line should have as large a trace as possible to provide a low impedance path and reduce glitch effects on the supply line. Clocks and other fast switching digital signals should be shielded from other parts of the board by digital ground. Avoid crossover of digital and analog signals, if possible. When traces cross on opposite sides of the board, they should run at right angles to each other to reduce feedthrough effects through the board. The best technique is to use a multilayer board with ground and power planes, where the component side of the board is dedicated to the ground plane only and the signal traces are placed on the solder side. However, this is not always possible with a 2-layer board.

APPLICATIONS INFORMATION

The AD5821 is designed to drive both spring-preloaded and nonspring linear motors used in applications such as lens auto-focus, image stabilization, or optical zoom. The operation principle of the spring-preloaded motor is that the lens position is controlled by the balancing of a voice coil and spring. Figure 25 shows the transfer curve of a typical spring-preloaded linear motor for autofocus. The key points of this transfer function are displacement or stroke, which is the actual distance the lens moves in millimeters (mm) and the current through the motor, measured in milliamps (mA).

A start current is associated with spring-preloaded linear motors, which is a threshold current that must be exceeded for any displacement in the lens to occur. The start current is usually 20 mA or greater; the rated stroke or displacement is usually 0.25 mm to 0.4 mm; and the slope of the transfer curve is approximately 10 $\mu\text{m}/\text{mA}$ or less.

The AD5821 is designed to sink up to 120 mA, which is more than adequate for available commercial linear motors or voice coils. Another factor that makes the AD5821 the ideal solution for these applications is the monotonicity of the device, ensuring that lens positioning is repeatable for the application of a given digital word.

Figure 26 shows a typical application circuit for the AD5821.

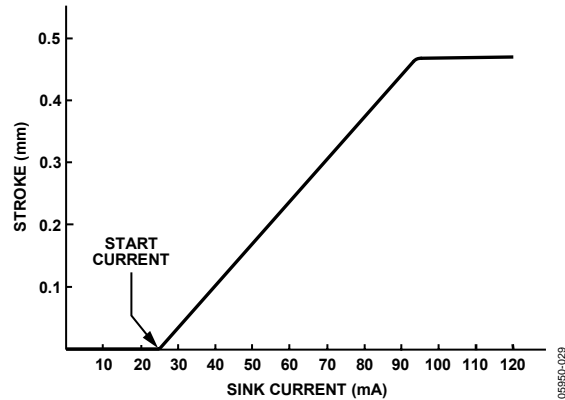


Figure 25. Spring-Preloaded Voice Coil Stroke vs. Sink Current

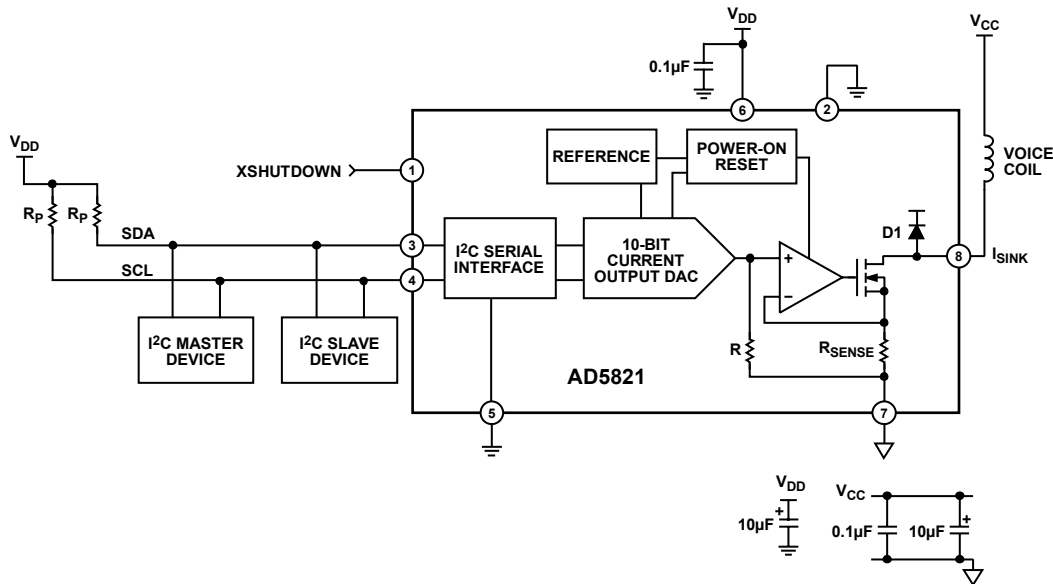


Figure 26. Typical Application Circuit

OUTLINE DIMENSIONS

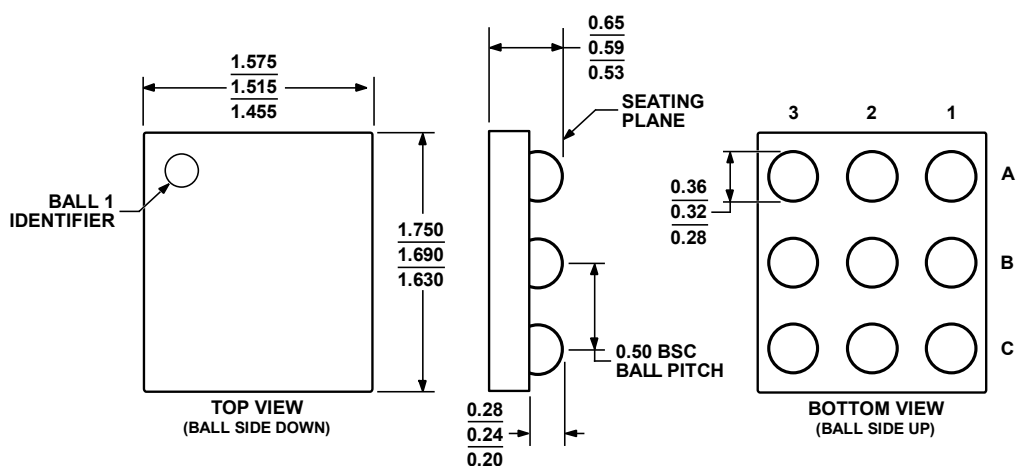


Figure 27. 9-Ball Wafer Level Chip Scale Package [WLCSP]
(CB-9-1)
Dimensions shown in millimeters

1104050

ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option	Branding
AD5821BCBZ-REEL ¹	-40°C to +85°C	9-Ball Wafer Level Chip Scale Package (WLCSP)	CB-9-1	D82
AD5821BCBZ-REEL ¹	-40°C to +85°C	9-Ball Wafer Level Chip Scale Package (WLCSP)	CB-9-1	D82
AD5821-WAFER	-40°C to +85°C	Bare Die Wafer		
AD5821D-WAFER	-40°C to +85°C	Bare Die Wafer on Film		
EVAL-AD5821EBZ ¹		Evaluation Board		

¹ Z = Pb-free part.

AD5821

NOTES

Purchase of licensed I²C components of Analog Devices or one of its sublicensed Associated Companies conveys a license for the purchaser under the Philips I²C Patent Rights to use these components in an I²C system, provided that the system conforms to the I²C Standard Specification as defined by Philips.

©2007 Analog Devices, Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners.
D05950-0-1/07(0)



www.analog.com